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December 2013

FQP2P40

P-Channel QFET $^{\rm @}$ MOSFET -400 V, -2.0 A, 6.5 Ω

Description

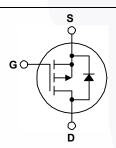
These P-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, planar stripe, DMOS technology.

This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. These devices are well suited for electronic lamp ballast based on complimentary half bridge.

Features

- -2.0 A, -400 V, $R_{DS(on)}$ = 6.5 Ω (Max.) @ V_{GS} = -10 V
- Low Gate Charge (Typ. 10 nC)
- Low Crss (Typ. 6.5 pF)
- · Fast Switching
- 100% Avalanche Tested
- · Improved dv/dt Capability





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FQP2P40_F080	Unit	
V_{DSS}	Drain-Source Voltage		-400	V	
I _D	Drain Current - Continuous (T _C = 25°C)		-2.0	Α	
	- Continuous (T _C = 100°	C)	-1.27	Α	
I _{DM}	Drain Current - Pulsed	(Note 1)	-8.0	Α	
V_{GSS}	Gate-Source Voltage		± 30	V	
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		120	mJ	
l _{AR}	Avalanche Current	(Note 1)	-2.0	Α	
E _{AR}	Repetitive Avalanche Energy	(Note 1)	6.3	mJ	
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	-4.5	V/ns	
P _D	Power Dissipation (T _C = 25°C)		63	W	
	- Derate Above 25°C		0.51	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C	
T _L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300	°C	

Thermal Characteristics

Symbol	Parameter	FQP2P40_F080	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	1.98	°C/W	
$R_{\theta CS}$	Thermal Resistance, Case-to-Sink, Typ.	0.5	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W	

Package Marking and Ordering Information

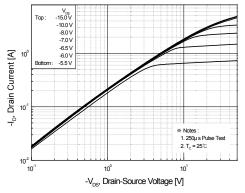
Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQP2P40_F080	FQP2P40	TO-220	Tube	N/A	N/A	50 units

Florical Characteristics

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-400			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = -250 μA, Referenced to 25°C		-		V/°C
I _{DSS}	Zero Cata Valta sa Duain Cumant	V _{DS} = -400 V, V _{GS} = 0 V			-1	μА
Zero	Zero Gate Voltage Drain Current	V _{DS} = -320 V, T _C = 125°C			-10	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = -30 V, V _{DS} = 0 V			-100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = 30 V, V _{DS} = 0 V			100	nA
On Cha	aracteristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$	-3.0		-5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = -10 V, I _D = -1.0 A		5.0	6.5	Ω
9 _{FS}	Forward Transconductance	V _{DS} = -50 V, I _D = -1.0 A		1.42		S
Dynam	ic Characteristics			•		
C _{iss}	Input Capacitance	$V_{DS} = -25 \text{ V}, V_{GS} = 0 \text{ V},$		270	350	pF
C _{oss}	Output Capacitance	f = 1.0 MHz		45	60	pF
C _{rss}	Reverse Transfer Capacitance			6.5	8.5	pF
Switchi	ing Characteristics					
t _{d(on)}	Turn-On Delay Time	V _{DD} = -200 V, I _D = -2.0 A,		9	30	ns
t _r	Turn-On Rise Time	$V_{GS} = -10 \text{ V}, R_{G} = 25 \Omega$		33	75	ns
t _{d(off)}	Turn-Off Delay Time	VGS 10 V, NG 20 11		22	55	ns
t _f	Turn-Off Fall Time	(Note 4)	/	25	60	ns
Qg	Total Gate Charge	V _{DS} = -320 V, I _D = -2.0 A,		10	13	nC
Q _{gs}	Gate-Source Charge	V _{GS} = -10 V	/	2.1		nC
Q _{gd}	Gate-Drain Charge	(Note 4)		5.5		nC
				•		
Drain-S	Source Diode Characteristics at	nd Maximum Ratings				
I _S	Maximum Continuous Drain-Source Diode Forward Current				-2.0	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				-8.0	Α
V_{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{S} = -2.0 \text{ A}$			-5.0	V
t _{rr}	Reverse Recovery Time	$V_{GS} = 0 \text{ V}, I_{S} = -2.0 \text{ A},$		250		ns
Q_{rr}	Reverse Recovery Charge	dI _F / dt = 100 A/μs		0.85		μC

- 1. Repetitive rating : pulse-width limited by maximum junction temperature.
- 2. L = 52.5 mH, I $_{AS}$ = -2.0 A, V $_{DD}$ = -50 V, R $_{G}$ = 25 Ω , Starting T $_{J}$ = 25°C.
- 3. I $_{SD} \leq$ -2.0 A, di/dt \leq 200 A/µs, V $_{DD} \leq$ BV $_{DSS,}$ Starting T $_{J}$ = 25°C.
- 4. Essentially independent of operating temperature.

Typical Performance Characteristics



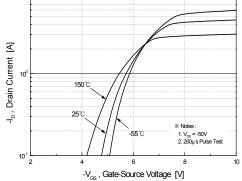
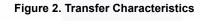
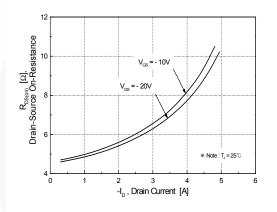


Figure 1. On-Region Characteristics





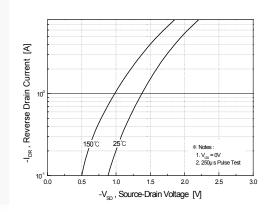
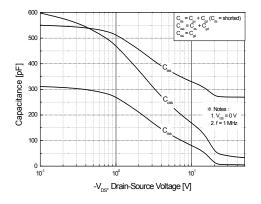


Figure 3. On-Resistance Variation vs. **Drain Current and Gate Voltage**

Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature



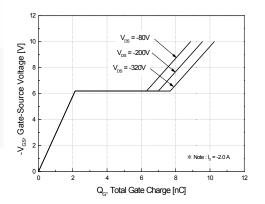
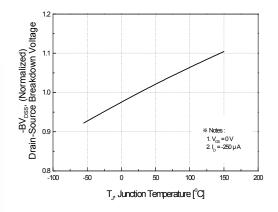


Figure 5. Capacitance Characteristics

Figure 6. Gate Charge Characteristics

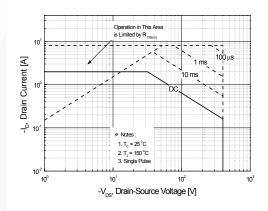
Typical Performance Characteristics (Continued)



25 (Nomalized) 1.5 (Nomalized)

Figure 7. Breakdown Voltage Variation vs. Temperature

Figure 8. On-Resistance Variation vs. Temperature



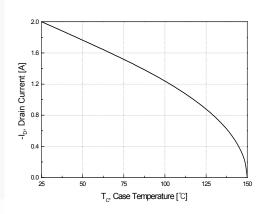


Figure 9. Maximum Safe Operating Area

Figure 10. Maximum Drain Current vs. Case Temperature

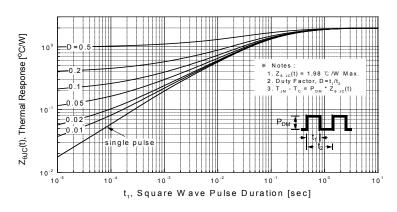


Figure 11. Transient Thermal Response Curve

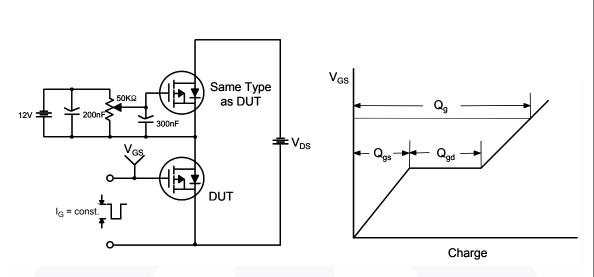


Figure 12. Gate Charge Test Circuit & Waveform

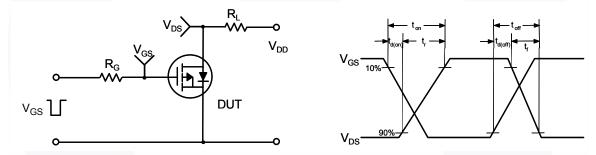


Figure 13. Resistive Switching Test Circuit & Waveforms

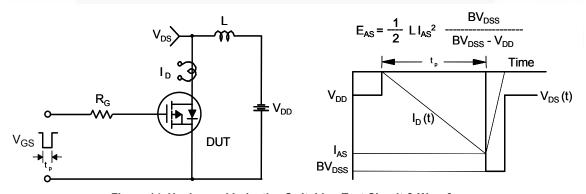
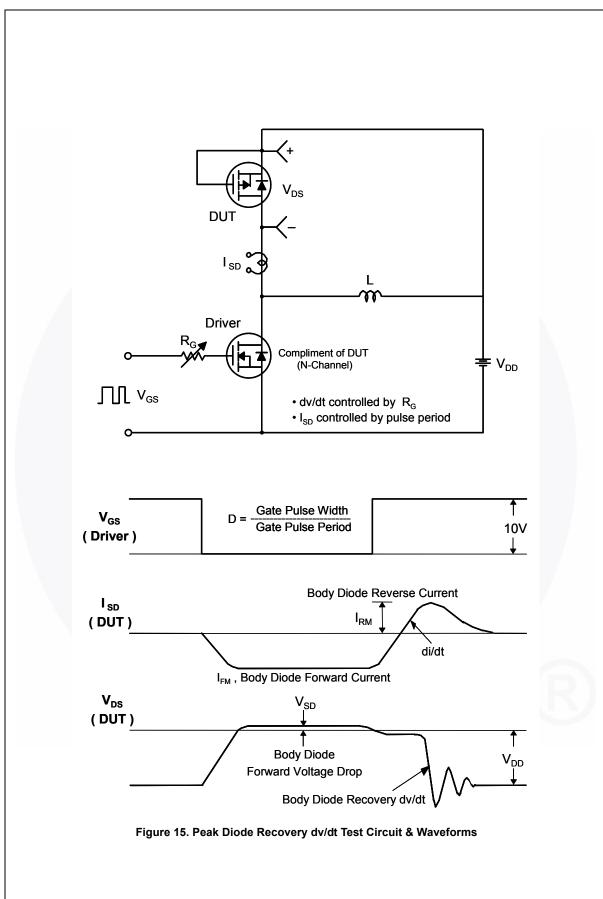


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



Mechanical Dimensions

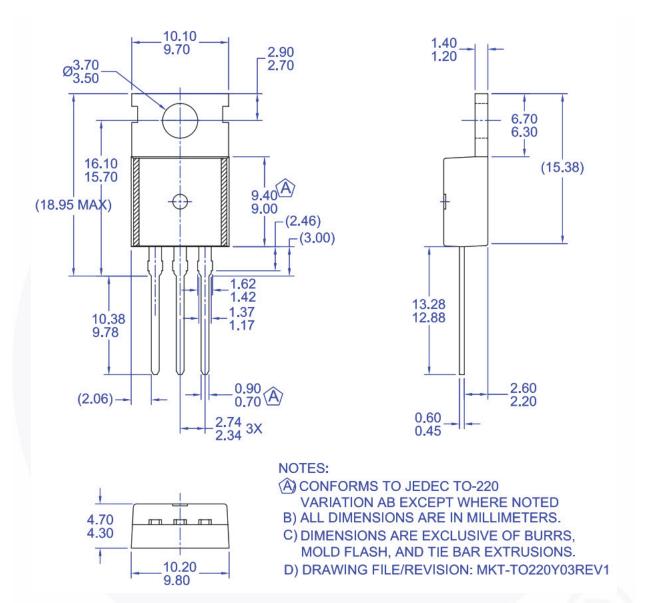


Figure 16. TO220, Molded, 3-Lead, Jedec Variation AB

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